

3.2.7 Summary to: Polarization Mechanisms

(Dielectric) polarization mechanisms in dielectrics are all mechanisms that

1. Induce dipoles at all (always with μ in field direction)
⇒ Electronic polarization.
2. Induce dipoles already present in the material to "point" to some extent in field direction.
⇒ Interface polarization.
⇒ Ionic polarization.
⇒ Orientation polarization.

Electronic polarization describes the separation of the centers of "gravity" of the electron charges in orbitals and the positive charge in the nucleus and the dipoles formed this way. it is always present

- It is a very weak effect in (more or less isolated) atoms or ions with spherical symmetry (and easily calculated).
- It can be a strong effect in e.g. covalently bonded materials like **Si** (and not so easily calculated) or generally, in solids.

Ionic polarization describes the net effect of changing the distance between neighboring ions in an ionic crystal like **NaCl** (or in crystals with some ionic component like **SiO₂**) by the electric field

- Polarization is linked to bonding strength, i.e. Young's modulus Y . The effect is smaller for "stiff" materials, i.e. $P \propto 1/Y$

Orientation polarization results from minimizing the free enthalpy of an ensemble of (molecular) dipoles that can move and rotate freely, i.e. polar liquids.

- It is possible to calculate the effect, the result invokes the Langevin function

$$L(\beta) = \coth(\beta) - \frac{1}{\beta}$$

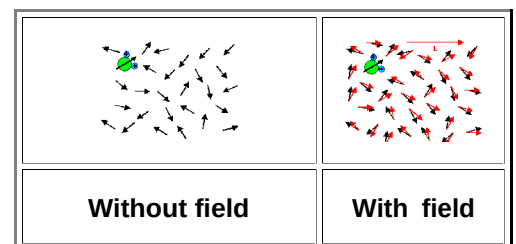
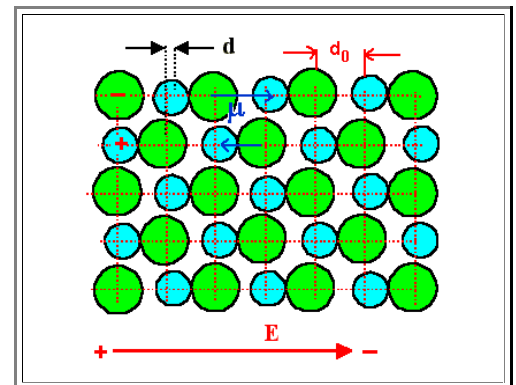
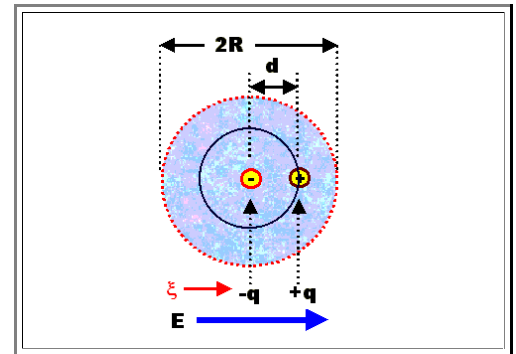
- In a good approximation the polarization is given by ⇒

The induced dipole moment μ in all mechanisms is proportional to the field (for reasonable field strengths) at the location of the atoms / molecules considered.

- The proportionality constant is called polarizability α ; it is a microscopic quantity describing what atoms or molecules "do" in a field.

Quantitative considerations of polarization mechanisms yield

- Justification (and limits) to the $P \propto E$ "law"
- Values for χ
- $\chi = \chi(\omega)$
- $\chi = \chi(\text{structure})$

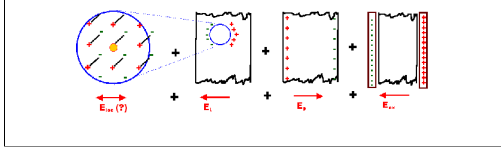


$$\langle P \rangle = \frac{N \cdot \mu^2 \cdot E}{3kT}$$

$$\underline{\mu} = \alpha \cdot E_{loc}$$

- The local field, however, is not identical to the macroscopic or external field, but can be obtained from this by the Lorentz approach
- For isotropic materials (e.g. cubic crystals) one obtains

$$E_L = \frac{P}{3\epsilon_0}$$



$$E_{loc} = E_{ex} + E_{pol} + E_L + E_{near}$$

Knowing the local field, it is now possible to relate the microscopic quantity α to the macroscopic quantity ϵ or ϵ_r via the Clausius - Mosotti equations $\Rightarrow$

- While this is not overly important in the engineering practice, it is a momentous achievement. With the Clausius - Mosotti equations and what went into them, it was possible for the first time to understand most electronic and optical properties of dielectrics in terms of their constituents (= atoms) and their structure (bonding, crystal lattices etc.)
- Quite a bit of the formalism used can be carried over to other systems with dipoles involved, in particular magnetism = behavior of magnetic dipoles in magnetic fields.

$$\frac{N \cdot \alpha}{3 \epsilon_0} = \frac{\epsilon_r - 1}{\epsilon_r + 2}$$

$$= \frac{\chi}{\chi + 3}$$

Questionnaire

Multiple Choice questions to all of 3.1